TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HCT540AP,TC74HCT540AF,TC74HCT540AFW TC74HCT541AP,TC74HCT541AF,TC74HCT541AFW

Octal Bus Buffer with TTL Input Level

TC74HCT540AP/AF/AFW Inverting, 3-State Outputs TC74HCT541AP/AF/AFW Non-Inverting, 3-State Outputs

The TC74HCT540A/TC74HCT541A are high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C²MOS technology.

These devices may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

They achive the high speed operation similar to equivalent LSTTL while maintaing the CMOS low power dissipation.

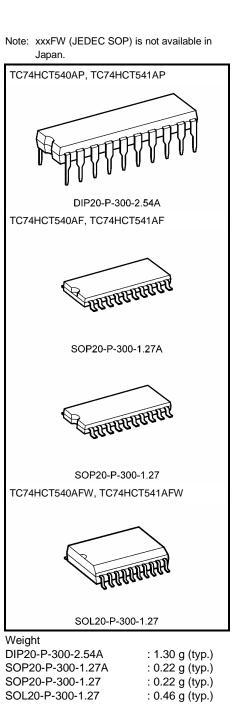
The TC74HCT540A is an inverting type, and the TC74HCT541A is a non-inverting type.

When either $\overline{G}1$ or $\overline{G}2$ are high, the terminal outputs are in the high-impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

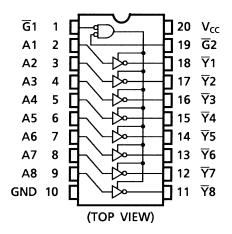
- High speed: $t_{pd} = 10 \text{ ns}$ (typ.) at VCC = 5 V
- Low power dissipation: $I_{CC} = 4 \mu A \pmod{at Ta} = 25 \circ C$
- Compatible with TTL outputs: $V_{IL} = 0.8 V (max)$ $V_{IH} = 2.0 V (min)$
- Wide interfacing ability: LSTTL, NMOS, CMOS
- Output drive capability: 15 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 6 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74LS540/541



<u>TOSHIBA</u>

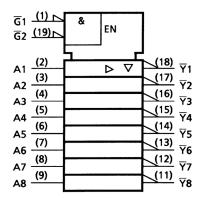
Pin Assignment

TC74HCT540A



IEC Logic Symbol

TC74HCT540A



Truth Table

	Inputs	Outputs			
G1	G2 An		Yn*	Yn ∗	
Н	Х	Х	Z	Z	
Х	Н	Х	Z	Z	
L	L	Н	Н	L	
L	L	L	L	Н	

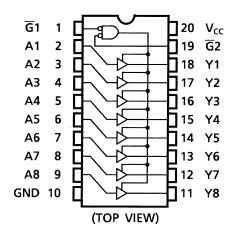
X: Don't care

Z: High impedance

*: Yn.....HCT541A

YnHCT540A

TC74HCT541A



TC74HCT541A

<u>G1 (1) </u> <u>G2 (19)</u>	& EN	
A1 (2) A2 (3) A3 (5) A4 (6) A5 (7) A6 (8) A7 (9) A8		(18) Y1 (17) Y2 (16) Y3 (15) Y4 (14) Y5 (13) Y6 (12) Y7 (11) Y8

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input diode current	I _{IK}	±20	mA
Output diode current	I _{OK}	±20	mA
DC output current	IOUT	±35	mA
DC V _{CC} /ground current	ICC	±75	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5~5.5	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	t _r , t _f	0~500	ns

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
Sinalacteristics Symbo				$V_{CC}(V)$	Min	Тур.	Max	Min	Max	Onit
High-level input voltage	VIH	—		4.5~5.5	2.0			2.0	_	V
Low-level input voltage	V _{IL}	—		4.5~5.5	_	_	0.8	_	0.8	V
High-level output	Varia	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -20 \ \mu A$	4.5	4.4	4.5	_	4.4	_	V
voltage	V _{ОН}		$I_{OH} = -6 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	
Low-level output voltage	V _{OL}	VIN = VIH or VIL	$I_{OL}=20~\mu A$	4.5	_	0.0	0.1	_	0.1	V
			$I_{OL} = 6 \text{ mA}$	4.5		0.17	0.26	_	0.33	
3-state output off-state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		5.5	_		±0.5	_	±5.0	μА
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		5.5			±0.1	_	±1.0	μA
Quiescent supply - current	Icc	$V_{IN} = V_{CC}$ or GND		5.5		_	4.0		40.0	μA
	Ι _C	Per input: $V_{IN} = 0.5$ V or 2.4 V Other input: V_{CC} or GND		5.5			2.0	_	2.9	mA

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
Unaracteristics	Symbol		CL (pF)	$V_{CC}(V)$	Min	Тур.	Max	Min	Max	Unit
Output transition time	t _{TLH}		50	4.5		7	12	_	15	ns
	tTHL		50	5.5		6	11	—	14	
			50	4.5	_	12	20	—	25	
Propagation delay time	t _{pLH}			5.5		9	18	—	23	ns
(TC74HCT540A)	t _{pHL}		150	4.5	_	17	26	—	33	115
			100	5.5		14	24	—	30	
	^t pLH ^t pHL	_	50	4.5	_	14	23	—	29	ns
Propagation delay time			50	5.5	_	11	21		27	
(TC74HCT541A)			150	4.5	_	19	29	—	36	
				5.5	_	16	27		33	
	t _{pZL}	$R_L = 1 k\Omega$	50	4.5	_	18	30	—	38	ns
Output enable time				5.5		16	27	—	35	
	t _{pZH}		150	4.5	_	23	36	—	45	
			100	5.5	_	21	33		41	
Output disable time	t _{pLZ}	$R_I = 1 k\Omega$	50	4.5	_	18	30	—	38	ns
	t _{pHZ}		00	5.5	_	16	27		35	115
Input capacitance	CIN	—				5	10	—	10	pF
Output capacitance	C _{OUT}	_	_			10		_	_	pF
Power dissipation	C _{PD}	TC74HCT540A				35		_	_	pF
capacitance	(Note)	TC74HCT541A				31	_	_		μr

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

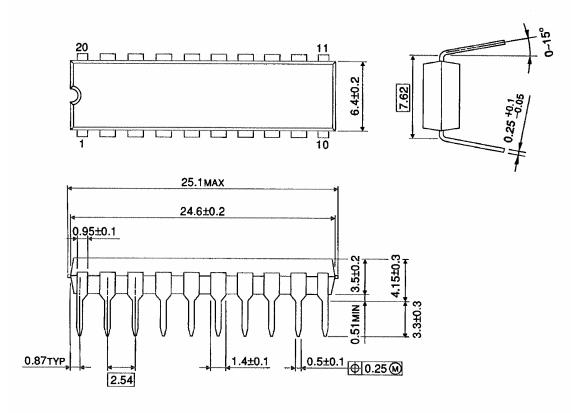
Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per bit)

Package Dimensions

DIP20-P-300-2.54A

Unit : mm



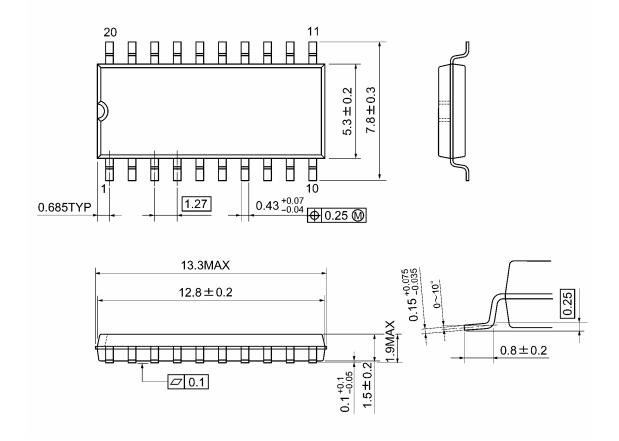
Weight: 1.30 g (typ.)

TOSHIBA

Package Dimensions

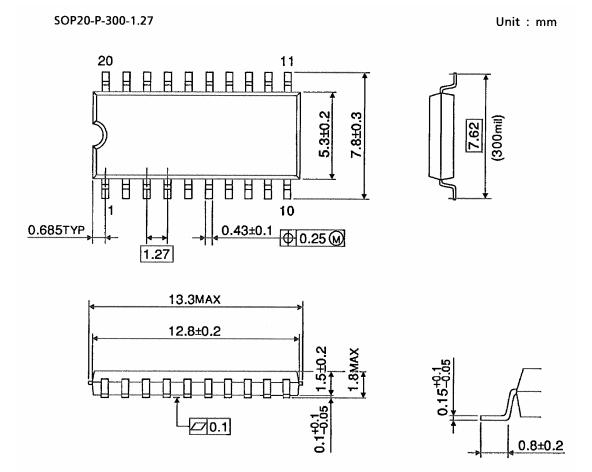
SOP20-P-300-1.27A

Unit: mm



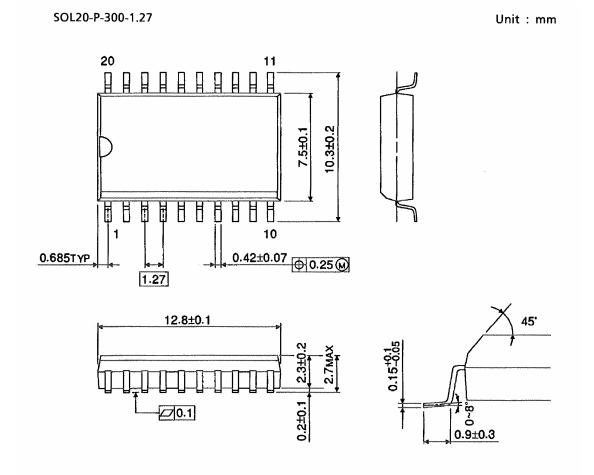
Weight: 0.22 g (typ.)

Package Dimensions



Weight: 0.22 g (typ.)

Package Dimensions (Note)



Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

Note: Lead (Pb)-Free Packages DIP20-P-300-2.54A SOP20-P-300-1.27A

RESTRICTIONS ON PRODUCT USE

Handbook" etc. 021023_A

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